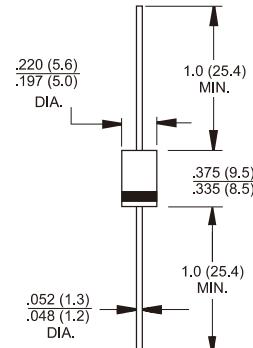




31DF4 - 31DF6 3.0 AMPS. Super Fast Rectifiers

DO-201AD



Dimensions in inches and (millimeters)



Marking Diagram

31DFX = Specific Device Code
G = Green Compound
Y = Year
WW = Work Week

Features

- ◊ High efficiency, Low VF
- ◊ High current capability
- ◊ High reliability
- ◊ High surge current capability
- ◊ Low power loss.
- ◊ Green compound with suffix "G" on packing code & prefix "G" on datecode.

Mechanical Data

- ◊ Cases: Molded plastic
- ◊ Epoxy: UL 94V-0 rate flame retardant
- ◊ Lead: Pure tin plated, Lead free., solderable per MIL-STD-202, Method 208 guaranteed
- ◊ Polarity: Color band denotes cathode end
- ◊ High temperature soldering guaranteed: 260°C/10 seconds/.375", (9.5mm) lead lengths at 5 lbs., (2.3kg) tension
- ◊ Weight: 1.20 grams

Maximum Ratings and Electrical Characteristics

Rating at 25°C ambient temperature unless otherwise specified.

Single phase, half wave, 60 Hz, resistive or inductive load.

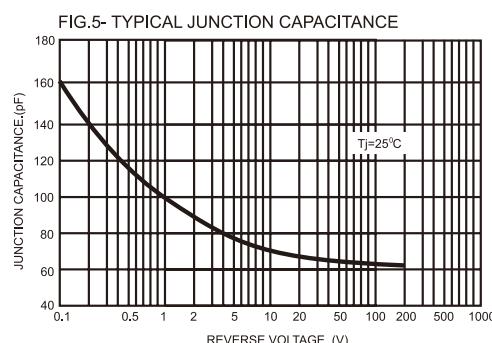
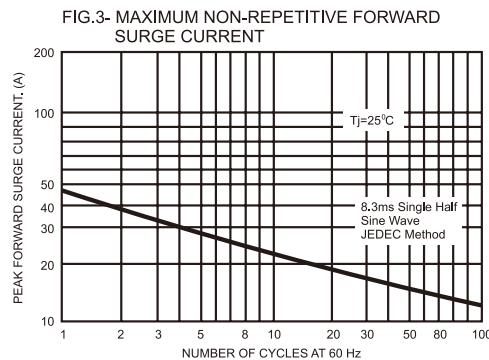
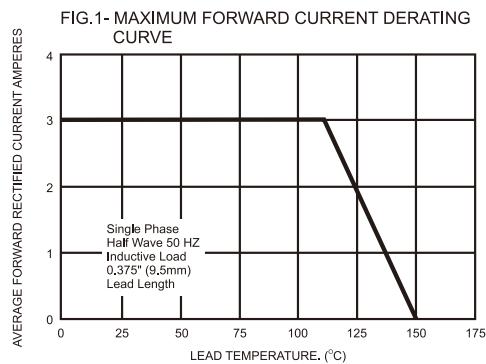
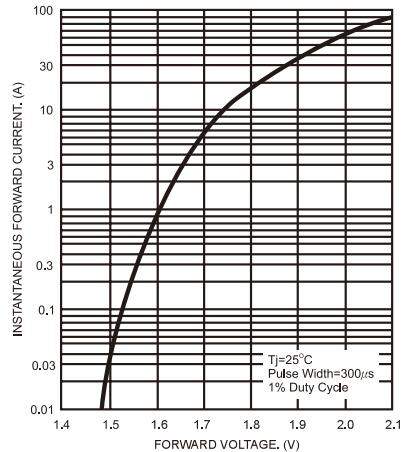
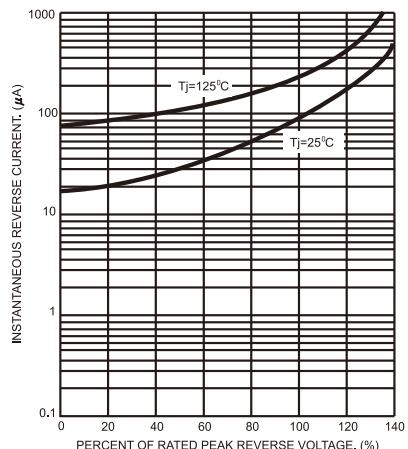
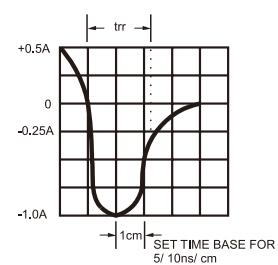
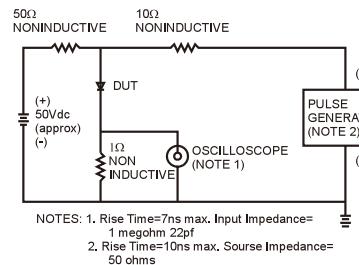
For capacitive load, derate current by 20%

Type Number	Symbol	31DF4	31DF6	Units
Maximum Recurrent Peak Reverse Voltage	VR _{RM}	400	600	V
Maximum RMS Voltage	VR _M S	280	420	V
Maximum DC Blocking Voltage	V _{DC}	400	600	V
Maximum Average Forward Rectified Current .375 (9.5mm) Lead Length @T _A = 29°C @T _L = 109°C	I _F (AV)	1.2 3.0		A
Peak Forward Surge Current, 8.3 ms Single Half Sine-wave Superimposed on Rated Load (JEDEC method)	I _{FSM}	45		A
Maximum Instantaneous Forward Voltage @ 3.0A	V _F	1.7		V
Maximum DC Reverse Current at @ T _A =25°C Rated DC Blocking Voltage (Note 1) @T _A =125°C	I _R	20 100		uA uA
Maximum Reverse Recovery Time (Note 3)	T _{rr}	35		nS
Typical Thermal Resistance (Note 2)	R _{θJA}	80		°C/W
Operating Temperature Range	T _J	-40 to +150		°C
Storage Temperature Range	T _{STG}	-40 to +150		°C

Notes: 1. Pulse Test with PW=300 usec, 1% Duty Cycle

2. Thermal Resistance from Junction to Ambient .375" (9.5mm) Lead Length.

3. Reverse recovery Test Condition: T_a = 25°C, IFM=3A, dI/dt = 50A / Us.

RATINGS AND CHARACTERISTIC CURVES (31DF4 THRU 31DF6)

FIG.2- TYPICAL FORWARD CHARACTERISTICS

FIG.4- TYPICAL REVERSE CHARACTERISTICS

FIG.6- REVERSE RECOVERY TIME CHARACTERISTIC AND TEST CIRCUIT DIAGRAM


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